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First principles investigation into the phase stability and enhanced hardness of TiN-ScN and TiN-YN alloys



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ABSTRACT

We study the phase stability, mechanical properties, and electronic structure of two quasi-binary ceramic systems, $Ti_{1.x}Sc_xN$ and $Ti_{1.x}Y_xN$ ($0 \le x \le 1$), using first principles methods based on density functional theory, cluster expansion formalism, and Monte Carlo techniques. Owing to the similarity in ionic radii and electronegativities of their respective transition metals, strong exothermic mixing of TiN and ScN is predicted, with four ordered intermetallic phases lying on the convex hull: TiScN₂, TiSc₉N₉, TiSc₉N₁₀, and Ti₃Sc₂N₅. These structures form layered rocksalt-type configurations to minimize strain energy while maximizing occupation of bonding states. The fully-detailed phase diagram including these predicted ground states and known end members is constructed, revealing an upper consolute temperature of 660 K. In contrast to $Ti_{1.x}Sc_xN$, the mismatched properties of TiN and YN lead to large structural distortions and positive strain energies. As a result, endothermic mixing with significant upward bowing in the formation energy is observed at intermediate concentrations, with the consolute temperature of 7225 K being predicted from the phase diagram of $Ti_{1.x}Y_xN$. TiN, ScN, and YN are found to display hardness values of 23.4, 25.1, and 20.6 GPa respectively, in good agreement with experimental data. The intermetallic phase $Ti_{3}Sc_{2}N_{5}$ is predicted to exhibit an exceptionally high hardness of 27.3 GPa. From analysis of projected electronic density of states and Crystal Orbital Hamiltonian Populations, we attribute enhanced hardness to strong nitrogen *p* and metal *d* hybridization, being related to minimal 3*d* t_{2g} occupation. These features extend to the case of random solutions, which we model using special quasirandom structures, showing a maximum hardness at a valence electron concentration of 8.4. Based on these findings, we suggest $Ti_{1.x}Sc_xN$ alloys for implementation in hard coating applications.

1. Introduction

During past couple of decades, transition metal (M) nitrides (TMNs) have drawn significant attention as coating materials due to their high hardness, as well as their resistance to wear and oxidation [1-12]. Many TMNs of the cubic binary form have been explored in the quest for hard coating materials [13-21]. Of these, TiN remains the most widely used compound for modern applications due to its high hardness, robust thermal stability, and low cost of synthesis [22-26]. However, recent works have shown that improved properties may be achieved by alloying TiN with various other transition metals, such as Zr, Hf, V, Nb, Ta, Mo, W [27-37]. Generally, substitution of Ti with these elements, which causes an increase in the valence electron concentration (VEC), leads to enhanced ductility and toughness, coupled with decreased hardness. In contrast, Jhi and Ihm showed that hardness can be increased by decreasing the VEC through replacement of nitrogen with carbon in the TiC_xN_{1-x} system [3,4]. Further work by Holleck indicated that the hardness of carbonitrides is maximized at a VEC of 8.4 electrons per formula unit [7]. These findings suggest a pathway to enhanced hardness in alloys through changes in bonding

behavior, which may also affect microstructural features, which may be influenced by VEC.

Recent investigation into TiN-AlN alloys, synthesized with epitaxial ScN inclusion, have shown enhanced hardness with respect to the end members; however, the application of this system is limited due to its low maximum operating temperature and phase decomposition [38]. Despite their limitations in terms of stability, the properties of $Ti_{1-x}Al_xN$ support the theory that mechanical properties of TMN alloys may be finely tuned through controlled electron valency. $Ti_{1-x}Sc_xN$ has also been studied, showing thermodynamic stability throughout a much wider range of temperatures and concentrations than $Ti_{1-x}Al_xN$, though the electronic and mechanical properties remain unexplored [39,40]. Considering the similarity in VEC between $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Al_xN$, as well as previous findings regarding the carbonitrides, increased hardness is likely in the TiN-ScN system. If this prediction is confirmed, these alloys would be highly-suitable candidates for hard coating applications.

In this work, we aim to utilize the concept of alloy hardening through controlled VEC to engineer next-generation hard coating systems in the form of $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Y_xN$ alloys for $0 \le x \le 1$. We

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employ state-of-the-art computational modeling techniques based on density functional theory (DFT), cluster expansion (CE) techniques, and Monte Carlo (MC) formalisms to study the phase stability, electronic structure, and mechanical properties of these materials. In doing so, we identify several novel intermetallic phases exhibiting enhanced hardness with respect to the end members. Additionally, these properties are clearly explained through analysis of projected densities of states (PDOS) and Crystal Orbital Hamiltonian Populations (COHP), each of which elucidating the interplay between e_g -p hybridization and t_{2g} occupation. Our analysis is also extended to the high-temperature case of cation-disordered compounds, modeled by special quasirandom structures (SQS). The computed mechanical properties of these alloys enrich the database of hard coating materials, which may facilitate the experimental synthesis of such materials with appropriate material selection and design for hard coatings application.

2. Computational methods

We performed first-principles computations based on DFT using the Vienna Ab initio Simulation Package (VASP) [41-44]. The projector augmented wave (PAW) [45,46] method was implemented with the Perdew-Burke-Ernzerhof (PBE) generalized gradient approximation (GGA) [47,48]. Pseudo-potentials Ti_sv, Sc_sv and Y_sv, for which semicore s and p electrons are treated as valence states, and the standard N pseudopotential were chosen from the VASP database [49]. A 400 eV kinetic energy cut-off was selected for the plane-wave basis set in the expansion of electron-wave functions. For all the structures, Monkhorst-Pack k-points meshes [50-53] were created with k-points per reciprocal atom (KPPRA) of density 4000. Electronic minimization was done with Gaussian smearing of width 0.1 eV by setting the convergence criterion to 10⁻⁵ eV/atom, whereas, ionic relaxation was performed using conjugate-gradient algorithm with a force criterion of 0.02 eV/Å. For the end members TiN, ScN and YN, we fit the computed energies of 5 volumes, varied about the estimated minimum, to the 3rd order Birch-Murnaghan [54,55] equation of state, allowing accurate equilibrium energies, volumes, and bulk moduli to be obtained as described in earlier works [17-20,56,57].

The MIT Ab initio Phase Stability (maps) [58,59] code from the Alloy Theoretic Automated Toolkit (ATAT) package [58–61] was used to generate the CE and energy landscapes for $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Y_xN$ alloy systems. Their phase diagrams were generated from the output of Monte Carlo simulations performed using Easy Monte Carlo Code (emc2 and phb) [60,61] within ATAT. Phonon vibrational contributions were neglected.

To study the properties of random solid solution for these two alloy systems at varying atomic compositions, ranging from x = 0.125 to 0.875 in a step size of 0.125, we implemented SQS, which utilizes Monte Carlo simulations to achieve close approximations to completely disordered states by matching correlation functions within the CE formalism [62-64]. Each SQS, generated using the sqs2tdb code within ATAT [62–64], contained 64 total atoms with 32 exchangeable metal sites. Resulting correlation parameters, as defined in the work of A. Van de Walle et al. [64] are supplied in Table 1. These SQS's were used to compute the elastic constants using the energy-strain method from two robust Python workflow packages; pyvasp-workflow [65] and pydass_vasp [66], each of which implement routines from Pymatgen [67]. To obtain the three independent elastic constants, C_{11} , C_{12} and C_{44} for these random solid solutions assuming symmetry of the cubic rocksalt system with space group $Fm\overline{3}m$, the pymatgen elasticity package was used. Elastic constants for the end members and predicted ground states were also calculated using the method of energy-strain, i.e., applying strains to the unit cell and then fitting the energies and strains to a second order polynomial as detailed in [17-20,56,57]. For the intermetallic structures, which exhibit slight deviation from cubic symmetry of the rocksalt system, the elastic constants were averaged arithmetically over the directions as described in [37,68], i.e., C_{11} , C_{22} and C_{33} were averaged yielding \overline{C}_{11} , whereas, C_{44} , C_{55} and C_{66} were averaged yielding \overline{C}_{44} .

From these three independent elastic constants, other derived mechanical properties such as Bulk modulus (*B*), Shear modulus (*G*), Pugh's ratio (k), Poisson's ratio (ν), Young's modulus (*E*) were calculated using the following equations:

$$B = (C_{11} + 2C_{12})/3 \tag{1}$$

$$G_V = [(C_{11} - C_{12}) + 3C_{44}]/5$$
⁽²⁾

$$G_R = [5(C_{11} - C_{12}) C_{44}] / (4C_{44} + 3C_{11} - 3C_{12})$$
(3)

$$G = (G_V + G_R)/2 \tag{4}$$

$$k = G/B \tag{5}$$

$$\nu = (3 - 2k)/[2(3 + k)] \tag{6}$$

$$E = 9G/(3+k) \tag{7}$$

 $G_{\rm V}$ and $G_{\rm R}$ are polycrystalline shear modulus in Voigt and Reuss approximation while *G* is their Hill's arithmetic mean. The Vickers hardness ($H_{\rm V}$) of all structures in the Ti_{1-x}Sc_xN and Ti_{1-x}Y_xN alloy systems was calculated using the equation from Tian's model [69], given by,

$$H_{\rm V} = 0.92 \, k^{1.137} G^{0.708} \tag{8}$$

To test for the mechanical (elastic) stability of all the calculated structures, the following stability criteria of Born [70,71] were used,

$$C_{11} > C_{12}, C_{11} + 2C_{12} > 0, C_{44} > 0$$
(9)

We stress that the calculated values represent purely intrinsic properties, i.e., the effects of microstructure which may appear in experiment are not accounted for here.

To observe any correlation between the hardness of the SQS and the charge transfer from metal atoms to nitrogen atom, we utilized Bader charge analysis [72–75] with Bader's division scheme [76,77] using Fast Fourier Transform grids of $200 \times 200 \times 200$. The local density of states (LDOS) for the predicted ground states and end member compounds were calculated with GGA using tetrahedron method with Blochl corrections [78]. To investigate detailed bonding characteristics, COHP were computed using the LOBSTER package [79–83].

3. Results and discussions

3.1. Properties of end member compounds TiN, ScN, and YN

Calculated equilibrium lattice parameters, elastic constants (C_{11} , C_{12}, C_{44}), and derived moduli for the end member compounds are listed in Table 2. Experimental values, with which our data are in fair agreement, are also listed in Table 2 for comparison. TiN, ScN, and YN are found to exhibit volumes (per formula unit) of 19.2, 23.11, 19.53 in Å³. These cell sizes are directly linked to ionic radii of the corresponding transition metals: Ti^{4+} (0.61 Å), Sc^{3+} (0.75 Å) and Y^{3+} (0.9 Å) [92]. The elastic constants C_{11} and C_{12} are inversely related to cell volume owing to the weakened stiffness of corresponding metal-nitrogen bonds at increased lengths. In contrast, C_{44} shows no clear correlation with volume, but is instead more closely related to underlying electronic properties, as will be discussed in the next paragraph. In agreement with previous works [17-20], Vickers hardness (H_V) is shown to be strongly dependent on C_{44} , whereas C_{11} and C_{12} have only minor effects. The importance of C_{44} can be attributed to its shear-resistant nature, which is crucial to maintain high hardness within the rocksalt structure. Thus, TiN, ScN and YN all display high C44 values and hence good hardness H_V (23.4, 25.1 and 20.6 in GPa respectively), with ScN being the hardest compound among the three end members. These calculated values of hardness agree well with available experimental values [7,87,89]. We observe anticorrelation between the bulk (B), shear (G), and Young's moduli (E) with volume, i.e., materials

Table 1

Differences $(\Delta \rho_{\alpha})$ between correlations of the SQSs and associated target disordered states for clusters containing **n** (pairs, triplets etc.) sites. Zeroes represent a perfect match.

| n | $\Delta ho_{lpha}(1/8)$ | $\Delta ho_{lpha}(2/8)$ | $\Delta \rho_{\alpha}(3/8)$ | $\Delta ho_{lpha}(4/8)$ | $\Delta ho_{lpha}(5/8)$ | $\Delta \rho_{\alpha}(6/8)$ | Δ ρ _α (7/8) |
|---|--------------------------|--------------------------|-----------------------------|--------------------------|--------------------------|-----------------------------|-------------------------------|
| 2 | 0 | 0.0 | 0 | 0 | 0 | 0.0 | 0 |
| 2 | 0.0208 | 0.0 | 0.0208 | 0 | 0.0208 | 0.0 | 0.0208 |
| 2 | -0.0208 | 0.0 | -0.0208 | 0 | -0.0208 | 0.0 | 0.0208 |
| 2 | -0.0625 | -0.167 | -0.0625 | 0 | -0.0625 | -0.167 | -0.0625 |
| 2 | 0.0 | 0.0 | 0.0 | 0 | 0.0 | 0.0 | 0.0 |
| 2 | -0.0156 | 0.0 | -0.0156 | 0 | -0.0156 | 0.0 | -0.0156 |
| 3 | -0.0156 | 0.0 | -0.0521 | 0 | -0.0521 | 0.0 | -0.0156 |
| 3 | 0.00521 | 0.0 | 0.00156 | 0 | 0.00156 | 0.0 | 0.00521 |
| 3 | 0.0156 | 0.0 | 0.0156 | 0 | 0.0156 | 0.0 | 0.0156 |
| 3 | 0.0364 | 0.0 | 0.0528 | 0 | 0.0528 | 0.0 | 0.0364 |
| 3 | 0.00521 | 0.0 | -0.0260 | 0 | -0.0260 | 0.0 | 0.00521 |
| 3 | 0.00469 | 0.0 | 0.00156 | 0 | 0.00156 | 0.0 | 0.00469 |

exhibiting lower volume are more highly resistant to structural deformations. Hence, due to its relatively large volume, YN exhibits low bulk and shear moduli, leading to a low hardness of 20.6 GPa. We note that the bulk modulus is underestimated in TiN owing to overestimated volume, which is well-known result when utilizing GGA approximation in DFT calculations due to the under binding of chemical bonds as also found to be the case in the earlier work [17,28,29,34,37].

The mechanical properties of these end members, specifically C_{44} and hardness, can be explained through analysis of PDOS. As shown in Fig. 1, clear splitting of the metal t_{2g} and e_g states is observed due to the octahedral ligand field within the rocksalt structure. For all end members, the bonding e_g orbitals are completely occupied and exhibit significant σ overlap with the N *p* orbitals as reflected by strong *d*-*p* hybridization at low energies in the PDOS. Occupation of the t_{2g} orbitals, which exhibit minimal bonding-antibonding splitting, is strongly dependent on the transition metal. As TiN is nominally d^1 , it contributes

one itinerant electron to the partially-filled t_{2g} manifold and is therefore metallic. In contrast, the d^0 configurations of ScN and YN cause them to be zero-gap semiconductors [93] within the framework of GGA. However, the effects of electron correlation, arising from the presence of strongly localized 3*d* orbitals, are known to enhance the band gap magnitudes to approximately 0.9 eV for each compound [94–96].

With respect to hardness, the t_{2g} and e_g orbitals play opposing roles, i.e., occupied e_g bonding orbitals are strongly resistant to shearing and compression whereas, occupied t_{2g} orbitals favor shearing due to enhanced σ overlap among second-nearest neighbor metal atoms. To confirm these properties, which have been predicted by Jhi et al. [4], we have computed the PDOS for TiN with and without 10% shear strain applied in the [100] direction along the (010) face of the conventional cubic unit cell. We focus on two sets of orbitals which are significantly affected by this strain: the $d_{x^2-y^2}$ orbitals, which lie along the crystal axes forming strong nearest-neighbor (Ti–N) bonds, and the d_{xy}

Table 2

Lattice constant (*a*), volume per formula unit (V/f. u.), elastic constants (C_{11} , C_{12} , C_{44}), Bulk modulus (*B*), Shear modulus (*G*), Pugh's ratio (*k*), Poisson's ratio (ν), Young's modulus (*E*) and Vickers hardness (H_V) of the three end member compounds and the predicted four novel ground states. For the four intermetallic phases, volume per nitrogen atom (V/N) is provided for comparison.

| End members | a (Å) | V/f. u. (Å ³) | C ₁₁ (GPa) | C ₁₂ (GPa) | C ₄₄ (GPa) | B (GPa) | G (GPa) | k | ν | E (GPa) | H _V (GPa) |
|-----------------------------------|---|------------------------------|---------------------------------|--------------------------|--------------------------|---|------------|------|------|---------------------------|---|
| TiN | 4.25 4.245 ^a 4.21 ^e | 19.19 19.1 ^b | 582.2 | 122.6 | 158.9 | 275.8 318 ^{b,h} 303 ⁱ 267 ^j 290 ^k 280 ⁱ | 184.2 | 0.67 | 0.23 | 452.1 590° | 23.4 20.2 ^f 21 ^g |
| ScN | 4.52 4.501 ^d 4.52 ^e | 23.11 | 389.5 | 104.2 | 166.8 | $199.3 \\ 182 \pm 40^{d}$ | 156.7 | 0.79 | 0.19 | 372.5 388 ± 20^{d} | $\begin{array}{l} 25.1 \\ 24.4 \ \pm \ 1.3^d \end{array}$ |
| YN | 4.91 | 29.53 | 318.5 | 76.8 | 122.6 | 157.4 | 121.9 | 0.77 | 0.19 | 290.7 | 20.6 |
| Intermetallics | Lattice Type | V∕ N (Å ³) | <i>C</i> ₁₁ (GPa) | <i>C</i> 12 (GPa) | C 44 (GPa) | B (GPa) | G (GPa) | k | ν | E (GPa) | H _V (GPa) |
| TiScN ₂ | Rhombohedral | 20.57 | 483.4 | 135.4 | 186.5 | 251.4 | 181.4 | 0.72 | 0.21 | 438.7 | 25.2 |
| TiSc ₈ N ₉ | Hexagonal | 22.14 | 440.7 | 112.5 | 164.7 | 221.9 | 164.5 | 0.74 | 0.2 | 395.6 | 24.3 |
| TiSc ₉ N ₁₀ | Triclinic | 22.21 | 444 | 104.3 | 168.6 | 217.5 | 169.1 | 0.78 | 0.19 | 402.8 | 26.1 |
| $Ti_3Sc_2N_5$ | Monoclinic | 20.51 | 488.6 | 125.1 | 190.5 | 246.3 | 186.9 | 0.76 | 0.2 | 447.6 | 27.3 |

^a Expt. from [84].

^b Expt. from [85].

^c Expt. from [86].

^d Expt. from [87].

^e Expt. from [88].

^f Expt. from [89].

^g Expt. from [7]. ^h Expt. from [90].

ⁱ Expt. from [91].

^j GGA Calc. from [34].

^k GGA Calc. from [28].

¹ GGA Calc. from [17].



Fig. 1. Projected density of states (PDOS) of the end member compounds TiN, ScN and YN. The Fermi energy is set to zero in each panel. Red solid and green long-dashed lines represent the metallic t_{2g} and e_g states respectively while blue short-dashed lines indicate nitrogen p states. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

orbitals, which lie along the body-diagonals forming weak secondnearest-neighbor (Ti-Ti) bonds. Our results, displayed in Fig. 2 show two major changes in the features of the $d_{x^2-y^2}$ PDOS: (i) the maximum peak in the occupied densities increases from -5.2 eV to -4.4 eV, and (ii) overall occupation of the orbitals are decreased. Each of these effects, which lead to a large increase in the energy of the system, can be attributed to the bond angle deviation (from the ideal value of 90°) caused by shear strain, leading to decreased overlap and hybridization of the Ti $d_{x^2-y^2}$ and N *p* orbitals. In contrast, we observe the following changes in the features of the d_{xy} PDOS: (i) increased bonding-antibonding splitting throughout the energy range of 1 eV to 3 eV, and (ii) overall enhanced occupation of the orbitals. The changes, which slightly decrease the energy of the system, are facilitated by shorter Ti-Ti bond lengths across the body-diagonals of the cell as shear strain is applied, causing increased d_{xy} - d_{xy} overlap. Based on these results, we confirm that the metal $d e_g$ exhibit highly shear-resistant properties whereas the $d t_{2g}$ favor strain.

The filled e_g bonding states and unfilled t_{2g} nonbonding states of ScN allows it to retain a shear modulus and hardness higher than that of TiN, in which the t_{2g} states are partially filled. However, d-p hybridization is weaker in ScN owing to the low electronegativity of Sc. As for YN, the discussed effects of enhanced covalent interaction are dominated by the large volume expansion as discussed previously, leading to decreased hardness. Therefore, to achieve maximum hardness, we aim to balance highly covalent metal-nitrogen bonds, low occupation of the t_{2g} states, and minimal volume expansion.

3.2. Energy landscapes and phase diagrams

For the CE of $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Y_xN$, Table 3 summarizes the number of structures calculated with DFT, number of clusters (pairs, triplets and quadruplets) used, and cross-validation (CV) scores.



Fig. 2. Projected density of states (PDOS) for TiN, showing the Ti d_{xy} (top panel) and Ti $d_{x^2-y^2}$ orbitals with and without 10% shear strain applied in the [100] direction along the (010) face of the conventional cubic unit cell. The Fermi energy is set to 0 eV in each panel.

Table 3

Numbers of structures calculated with DFT, numbers of clusters in pairs, triplets and quadruplets, and cross-validation (CV) score of Ti_{1-x}Sc_xN and Ti_{1-x}Y_xN.

| $ \begin{array}{c cccc} Alloys & Num. of structures & Num. of clusters \\ (pair + trip + quad) & CV Score \\ (meV) \\ \hline Ti_{1,x}Sc_xN & 83 & 15 + 2 + 3 & 4.04 \\ Ti_{1,x}Y_xN & 91 & 16 + 12 + 16 & 19.3 \\ \end{array} $ | 1 1 | | · · · · · · · · · · · · · · · · · · · | 1 # # |
|---|---|--------------------|--|-------------------|
| $ \begin{array}{ccccc} Ti_{1,x}Sc_xN & 83 & 15+2+3 & 4.04 \\ Ti_{1,x}Y_xN & 91 & 16+12+16 & 19.3 \end{array} $ | Alloys | Num. of structures | Num. of clusters (pair + trip + quad) | CV Score (meV) |
| | Ti _{1-x} Sc _x N Ti _{1-x} Y _x N | 83 91 | 15 + 2 + 3 16 + 12 + 16 | 4.04 19.3 |

Computed energy landscapes of the two quasi-binary systems, Ti1-xScxN and $Ti_{1-x}Y_xN$, are displayed in Fig. 3. We find that the mixture of TiN and YN is strongly endothermic and significant upward-bowing (concavity) is observed in the formation energies of all enumerated structures, with the formation energy reaching values as high as 500 meV per atom as seen in Fig. 3 (b). Such strong rise in enthalpy can be attributed to the large differences in the size, ionic radius, and electronegativity of Ti and Y [92,97], causing structural distortions (to be discussed in section 3.4) and strain energy in the resulting mixtures. Ti and Y display electronegativities of 1.32 and 1.11 respectively. Hence, this difference will lead to enhanced charge transfer according to the relation for charge transferred per atom, $\Delta Z_{\rm a},$ and the difference in electronegativity, $\Delta \phi$, $\Delta Z_a = (1.2) (1-c_a) (\Delta \phi)$ [98], where c_a is the concentration of metal A within the binary alloy system A_xB_{1-x}. As observed in Fig. 4., greater charge transfer, as well as larger differences in ionic radii, lead to substantial changes in the volume and therefore positive strain energy. As a result, the end members are the only stable



Fig. 3. Formation energy per formula unit of (a) $Ti_{1-x}Sc_xN$ and (b) $Ti_{1-x}Y_xN$. Blue crosses indicate structures enumerated by CE, red circles represent structures calculated directly by DFT, black squares correspond to predicted ground states, and cyan triangles represent the SQS. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

ground states of Ti_{1-x}Y_xN solid solution. However, contributions of configurational entropy to the Gibbs free energy of Ti_{1-x}Y_xN may be significant enough to stabilize random solutions throughout intermediate concentrations. Due to large formation energies of the enumerated structures, a large miscibility gap can be expected for this system.

As opposed to Ti_{1-x}Y_xN, exothermic mixing is possible in Ti_{1-x}Sc_xN due to the similarity of Ti and Sc in size, ionic radius, and electronegativity. The electronegativities of Ti and Sc, 1.32 and 1.2 respectively, are only slightly different; hence, only minor changes in charge transfer and volume occur as seen in Fig. 4. This allows the effects of chemical bonding, controlled mostly by changes in valency, to lower the overall energy of the system [99]. As shown in Fig. 3 (a), a decrease in formation energy with a downward-bowing (convexity) nature is observed for many enumerated structures at intermediate concentrations. We find four novel ground states which lie on the convex hull: TiScN₂, TiSc₈N₉, TiSc₉N₁₀, and Ti₃Sc₂N₅. Given that these phases have not yet been synthesized experimentally, we provide purely predictive findings. Their formation energies are -17.968, -16.832, -15.264 and - 17.987 in the units of meV respectively. All ground states are thermodynamically stable with Ti₃Sc₂N₅ being the most stable phase. As there are many enumerated structures exhibiting negative formation energy, disordering can be expected with the miscibility gaps closing at moderate temperatures.



Fig. 4. Bader charge transfer from metal (M) atoms to nitrogen (N) (top) and variation in the unit cell volume per formula unit (bottom) in the $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Y_xN$ alloy system as a function of 'Sc' concentration (x).

The calculated phase diagram of $Ti_{1-x}Y_xN$ is displayed in Fig. 5 (b). Ti_{1-x}Y_xN features a miscibility gap far above the room temperature. For this system, the upper consolute temperature (T_c), above which complete miscibility is achieved, is predicted to be 7225 K. Considering that melting will almost surely occur below this temperature, we conclude that alloying in the Ti_{1-x}Y_xN system may only be implemented at moderately low or high concentrations, for which configurational entropy dominates to allow solubility. In such a case, Y will diffuse into the grain boundaries and enhances the oxidation resistance and mechanical properties. Hence, the low solubility of YN provides opportunities to engineer hard coatings with segregated concentration variations as reported by Lewis et al. [100] and Choi et al. [101]. Detailed properties of these random solutions will be discussed in Section 3.3.

In Fig. 5 (a), boundaries representing phase equilibria of the novel ground states and end members corresponding to the $Ti_{1,x}Sc_xN$ system are shown. We identify five major phase regions representing stability of unique heterogenous mixtures. Region I, representing the coexistence of TiN and $Ti_3Sc_2N_5$, covers a significant portion of the phase diagram; this indicates high tolerance of these phases with respect to variance in composition and temperature. More specifically, stability is maintained throughout Sc concentrations ranging from about 0 to 50% and temperatures ranging from 0 to 500 K. $Ti_3Sc_2N_5$ also coexists with TiScN₂ in region III near concentrations of 50% at moderately low temperatures. The strong stability of $Ti_3Sc_2N_5$ can be attributed to its low formation energy with respect to the other ground states. Coexisting at higher temperatures (500 to 660 K) and moderate Sc concentrations (0 to 50%) is the mixture of TiN and TiScN₂ owing to





Fig. 5. Calculated phase diagrams of (a) $Ti_{1-x}Sc_xN$ and (a) $Ti_{1-x}Y_xN$. Blue crosses represent data points computed directly from Monte Carlo methods, whereas red lines indicate interpolations and extrapolations of this data. Regions for the Ti1-xScxN phase diagram are discussed in section 3.2. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

configurational entropy contributions of TiScN₂. Within this range of concentrations, the miscibility gap disappears above 660 K and complete miscibility is achieved. At higher Sc concentrations (> 50%), significantly different properties are observed. TiScN2 coexists with TiSc₈N₉ in region IV at Sc concentrations ranging from 50% to 90%. However, a random configuration becomes energetically favorable at a low temperature of about 225 K. In region V, characterized by stability of TiS₉cN₁₀ and ScN, miscibility occurs at an even lower temperature of only 65 K. As will be discussed in greater detail in Section 3.3, the low consolute temperature within this region of high Sc concentration can be attributed to the minimal formation energy difference between the SQS and ordered ground states. Our result of computed upper consolute temperature of 660 K, where the miscibility gap completely disappears for all concentration of Sc in the Ti_{1-x}Sc_xN quasy-binary system, compares well with the previous work of Kerdsongpanya et al. [39,40], in which they have used first-principles calculations to predict a typical temperature of 800 °C (1073 K) at which Sc_{1-x}Ti_xN changes its phase from ordered solid solution to disordered solid solution at x = 0.5. Our calculation also supports the experimental result of Gall et al. [102] in which they have demonstrated the synthesis of single-crystal rocksaltstructured Ti_{1-x}Sc_xN epitaxial layers by reactive magnetron sputtering at 750 °C.

Fig. 6. Computed Conventional unit cells of the predicted four novel ground states (a) TiScN₂, (b) TiSc₈N₉, (c) TiSc₉N₁₀ and (d) Ti₃Sc₂N₅. Blue, red and green spheres represent Ti, Sc and N atoms respectively. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

3.3. Properties of TiN-ScN intermediate phases

The intermetallics TiScN₂, TiSc₈N₉, TiSc₉N₁₀, Ti₃Sc₂N₅ are predicted to crystallize in rhombohedral, hexagonal, triclinic, and monoclinic symmetries respectively due to cation ordering. However, the rocksalt-type structure of the parent lattice is preserved in each case. Additionally, all structures are characterized by layering of Ti and Sc atoms, allowing strain energy to be minimized. Table 2 lists the lattice type, volume per nitrogen atom (V/N), three independent averaged elastic constants (\overline{C}_{11} , \overline{C}_{12} , \overline{C}_{44}) and derived moduli and constants for these intermediate phases, with detailed structures and lattice parameters provided in Fig. 6 and Table 4. As only slight deviations from cubic symmetry occur due to cation ordering and lattice strain, a nearly-ideal symmetrized elastic tensor corresponding to cubic symmetry remains, i.e., components within the following groups are nearly equal: (i) C₁₁, C₂₂, and C₃₃ (ii) C₄₄, C₅₅, and C₆₆ (ii) C₁₂, C₁₃, and C₂₃. Hence, average elastic constants (\overline{C}_{11} , \overline{C}_{12} , \overline{C}_{44}) are reported as discussed in the computational methods. Our results indicate that all four intermetallics, as with the end members, satisfy the mechanical stability criteria of Born [70,71]. As listed in Table 2, high hardness is achieved in the intermediate phases as compared to the end members, with Ti₃Sc₂N₅ being the hardest compound (27.3 GPa). A mild anticorrelation between volume and hardness is observed for all phases. As shown in the phase diagram of Ti1-xScxN system, Ti3Sc2N5 is thermodynamically stable throughout a wide range of temperature from 0 K up to almost 500 K in the Sc composition ranging from 0 to 50% as mentioned in previous section. Therefore, we suggest Ti₃Sc₂N₅ as a highlysuitable candidate for hard coating applications along with other three novel ground states as its competitors.

The high hardness of Ti₃Sc₂N₅ may be analyzed from a chemical and

Table 4

The structural details (Lattice type, Hermann-Mauguin^a notation for Space group - symbol and number, and Lattice parameters) of the four predicted novel ground states.

| Predicted ground states | Lattice - type | Space group and number | Lattice parameter |
|--|----------------|---------------------------|---|
| TiScN ₂ | Rhombohedral | R3m (166) | a = b = c = 5.35 Å, $\alpha = \beta = \gamma = 33.32^{\circ}$ |
| TiSc ₈ N ₉ | Hexagonal | P31 m (162) | a = b = 5.46 Å, c = 7.72 Å, $\alpha = \beta = 90^{\circ}, \gamma = 120^{\circ}$ |
| ${\rm TiSc_9N_{10}}$ | Triclinic | PĪ (2) | a = 5.46 Å, b = 6.31 Å, c = 7.06 Å, α = 102.91°, β = 97.39°, γ = 106.83° |
| Ti ₃ Sc ₂ N ₅ | Monoclinic | C2/m (12) | |

^a from Reference [103].



Fig. 7. (a) Projected density of states and (b) Crystal Orbital Hamiltonian Populations (COHP) for the predicted intermetallic $Ti_3Sc_2N_5$ having the highest hardness. M-N and M-M represents metal-metal and metal-nitrogen interactions respectively. Negative and positive values of COHP correspond to bonding and antibonding respectively. The Fermi energy is set to zero in each panel.

structural perspective. First, as shown in the PDOS in Fig. 7, exceptionally strong *d*-*p* hybridization is observed throughout a wide range of energies (-7 eV to -2 eV), being directly associated with strong σ overlap of the metal 3*d e*_g orbitals with the nitrogen *p* orbitals.

Table 5

Integrated projected-Crystal Orbital Hamilton Populations (-IpCOHP) values in eV for different bonding states (Metal: Metal and Metal: Nitrogen) for the three end members and four predicted novel ground states.

| Compound | M-N (-IpCOHP) | M-M (-IpCOHP) |
|--|---------------|---------------|
| TiN | 1.415 | 0.137 |
| ScN | 1.428 | 0.012 |
| YN | 2.420 | 0.009 |
| TiScN ₂ | 1.408 | 0.043 |
| Ti ₃ Sc ₂ N ₅ | 1.721 | 0.078 |
| TiSc ₈ N ₉ | 1.255 | -0.008 |
| TiSc ₉ N ₁₀ | 1.228 | -0.009 |
| | | |

Further insight into the M-N bond strength is provided by the COHP curves in Fig. 7, showing complete occupation of states with high bonding character. By integrating the COHP curves below the Fermi level, we obtain average M-N -IpCOHP and M-M -IpCOHP values for the end members as well as for the novel ground states and these values are listed in Table 5. The M-N -IpCOHP value of 1.721 eV for Ti₃Sc₂N₅ is significantly higher than that of the end member compounds, e.g., 1.415 eV and 1.428 eV for TiN and ScN respectively. Hence, greater covalent/directional character of these bonds leads to increased resistance to shearing and compression. Secondly, both the PDOS and COHP curves indicate decreased occupation of the metal t_{2g} orbitals, with respect to TiN, owing to the VEC of Ti₃Sc₂N₅ (8.6) being less than that of TiN (9). As discussed previously, shear modulus is maximized when occupation of the t_{2g} states, which favor shearing due to metalmetal bonding, is minimized. Lastly, Ti₃Sc₂N₅ displays the lowest volume of the intermetallic phases as reported in Table 2; thus, contributing further to its high hardness.

3.4. Effects of cation disorder

formation energies of the fully-relaxed SQS's are displayed in Fig. 3. For Ti_{1-x}Y_xN, these energies closely resemble the general trend of enumerated structures within the CE; significant upward-bowing is observed. Hence, the high consolute temperature of Ti_{1-x}Y_xN can be attributed to the large and unfavorable difference between the formation energies of the SQS at intermediate concentrations in comparison to those of the end members TiN and YN. As for Ti_{1-x}Sc_xN, the SQS formation energies are strongly dependent on composition. At low to intermediate Sc concentrations, the SQS energies lie about 20–30 meV/f.u. above those of the respective ground states, leading to miscibility at temperatures above 660 K. In contrast, the SQS energies at high Sc concentrations lie only slightly above (5–10 meV/f.u.) the convex hull, resulting in much lower consolute temperatures ranging from 65 to 225 K.

The energetics of these systems are closely related to their underlying structures. Fig. 8 displays distributions of nearest-neighbor metalnitrogen-metal bond angles within the SQS's of Ti_{1-x}Sc_xN and Ti_{1-x}Y_xN. As expected, cation-disordering causes numerous atomic displacements to occur within each locally octahedral environment. For Ti1-xYxN, these octahedral distortions become unusually large at intermediate concentrations, with individual bond angles varying by as much as 20°. Such major structural deviations, owing to the mismatch in ionic radii of Ti and Y, are known to enhance occupation of antibonding orbitals within octahedral ligand fields [104,105] and therefore cause energetic instability within Ti_{1-x}Y_xN. As for Ti_{1-x}Sc_xN, for which the cation radii are more similar, only minor distortions take place, with bond angles generally lying within the range of 86°-94°. Hence, this causes only a relatively low rise in the formation energy for Ti_{1-x}Sc_xN. Interestingly, at high Sc concentrations, some grouping of bond angles occurs above and below the ideal value of 90°. This effect, which minimizes strain, accounts for the lowered SQS formation energy at high Sc concentrations as shown in the energy landscape of Ti_{1-x}Sc_xN (Fig. 3 (a)). The



Fig. 8. Distribution of the metal-nitrogen-metal bond angles (degrees) within the SQS's of $Ti_{1-x}Sc_xN$ (top) and $Ti_{1-x}Y_xN$ (bottom) as a function of Sc and Y concentration.

findings here are similar to those previously reported for $Ti_{1-x}Al_xN$ [106], where the higher number of Ti–Al bonds lower the contribution of configurational entropy resulting into the increased formation energy and decreased solubility limit in rocksalt structured $Ti_{1-x}Al_xN$.

Although long-range order disappears above the upper consolute temperature (T_c) of the Ti_{1-x}Sc_xN system, some degree of short-range order may persist at temperatures slightly above T_c . To elucidate these effects, we have performed Monte Carlo simulations on 8000 atom cells representing the disordered state of Ti_{0.5}Sc_{0.5}N at temperature 550 K (slightly above the miscibility gap) and 1000 K (significantly above the miscibility gap). For all Ti sites within each structure, the number of nearest-neighbor Sc sites are calculated and compared with the corresponding value for structures containing completely random Ti/Sc occupation. Accordingly, the "deviation from randomness" is defined as (NMC - NR). Here NMC is the number of occurrences of a given Ti-Sc coordination number within the cell generated from Monte Carlo simulations. NR is its random limit, simulated by randomly sorting Ti/Sc sites throughout 20 separate structures and averaging all values to avoid any sampling error. For reference of magnitude, the random limit for Ti-Sc coordination of 6 is found to be approximately 920 occurrences within the 8000 atom cell. The results, shown in Fig. 9 indicate the importance of short-range ordering at sufficiently low temperatures. At 550 K, Ti_{0.5}Sc_{0.5}N displays a strong preference to maximize the number of Ti-Sc bonds, reflected by a large number of intermediate coordination values (5-7) with respect to the corresponding random values. This finding agrees with our previous analysis of energetics in section 3.2, as the Ti-Sc bonds are more stable than the Ti-Ti and Sc-Sc bonds. In contrast, configurational entropy dominates at higher



Fig. 9. Distribution of Ti-Sc coordination values, defined as the number of neighboring Sc atoms to the total number of Ti atoms, in $Ti_{0.5}Sc_{0.5}N$ simulated at 550 K and 1000 K within the formalism of Monte Carlo techniques on 8,000 atom cells. Values are given with respect to those of completely random Ti/Sc occupations. For comparison, the ordered structure of TiScN₂ exhibits Ti-Sc coordination of 6 at all anion sites, which therefore maximizes the total number of Ti-Sc bonds.

temperatures; short-range order almost completely disappears at 1000 K, i.e., the Ti–Sc coordination values are very nearly equal to those of the random values. Based on these results, we suggest that the structural and therefore mechanical properties of the $Ti_{1-x}Sc_xN$ random solid solutions may be finely tuned by synthesis at appropriate temperatures to achieve a specific degree of short-range order. Quenching may be utilized to freeze in these properties.

Elastic constants (C_{11} , C_{12} and C_{44}) and derived mechanical properties (bulk modulus, shear modulus, and Vickers hardness) of the SQS's are displayed in Fig. 10 as a function of Sc and Y concentration for Ti₁. _xSc_xN and Ti_{1-x}Y_xN respectively, with detailed numeric values listed in Table 6. All the random solid solutions satisfy the mechanical stability criteria of Born [13,14,70,71] as other compounds discussed previously. Our results show that bulk modulus, being directly related to C_{11} , and C_{12} , decreases at increased Sc and Y concentrations owing to volumetric expansion and decrease in metal-nitrogen bond length stiffness. Regarding C44 and the remaining moduli, significantly different behaviors are observed in Ti1-xScxN and Ti1-xYxN. In the latter, substantial weakening, reflected by decreases in shear moduli and hardness, occurs at higher Y concentrations. This result can be attributed to strong structural distortions, as well as the increase in spatial extent of the diffuse 4d orbitals contributed from Y, which are less shear-resistant than the strongly localized 3d orbitals of Ti. In contrast, $Ti_{1-x}Sc_xN$ exhibits an increase in C_{44} , and therefore in hardness, at intermediate concentrations. A maximum Vickers hardness of 27 GPa is found to occur at 62.5% atomic concentration of Sc, corresponding to a VEC of about 8.4. This result agrees with our earlier findings showing maximum hardness in the predicted intermetallic phase Ti₃Sc₂N₅ with intermediate VEC of 8.6. We also observe that the hardness of the random solution is very slightly lower (~0.3 GPa) than that of the ordered phase due to the enhanced structural distortions resulting from disorder.

Our findings regarding the correspondence of hardness with VEC indicate that the mechanical properties within $Ti_{1-x}Sc_xN$ are clearly influenced by electron valency. To further support this, the PDOS of the cation-disordered $Ti_{0.375}Sc_{0.625}N$ configuration is displayed in Fig. 11. In a similar manner to $Ti_3Sc_2N_5$, exceptionally strong *d-p* hybridization, mediated by σ -overlap of the highly-localized 3*d* e_g and 2*p* orbitals, is observed through a wide range of energies (-6 eV to -2 eV) below the Fermi level. Additionally, relatively minimal occupation of the 3*d* t_{2g}



Fig. 10. Elastic constants *C*11, *C*12, *C*44, bulk moduli (*B*), shear moduli (*G*) and Vickers hardness (*HV*) of the SQS's of $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Y_xN$. Points represent explicitly calculated values, whereas lines are interpolations.

orbitals occurs. Each of these factors contribute to the increased hardness of $Ti_{1-x}Sc_xN$ at the VEC of 8.4. These results agree well with the previously studied system of Tic_xN_{1-x} , which has been shown to exhibit maximum hardness at a VEC of 8.4 [7].

4. Conclusion

In summary, we have investigated the phase stability of two quasi-

Table 6

Concentration (x), elastic constants (C_{11} , C_{12} , C_{44}), Bulk modulus (B), Shear modulus (G), Pugh's ratio (k), Poisson's ratio (ν), Young's modulus (E) and Vickers hardness (H_V) of the SOS of Ti_{1-x}Sc_xN and Ti_{1-x}Y_xN.

| SQSs | Concentration (<i>x</i>) | C ₁₁ (GPa) | C ₁₂ (GPa) | C ₄₄ (GPa) | B (GPa) | G (GPa) | k | ν | E (GPa) | H _V (GPa) |
|------------------------------------|----------------------------|--------------------------|--------------------------|--------------------------|------------|------------|------|------|------------|-------------------------|
| | 0 | 563.2 | 113.1 | 158.6 | 263.1 | 182.5 | 0.69 | 0.22 | 444.7 | 24.2 |
| | 0.125 | 517.3 | 136.5 | 161.1 | 263.5 | 172.2 | 0.65 | 0.23 | 424.2 | 21.7 |
| | 0.25 | 497.6 | 129.9 | 159.5 | 252.4 | 168.8 | 0.67 | 0.23 | 414.2 | 22 |
| | 0.375 | 473.7 | 123.7 | 163.3 | 240.4 | 167.9 | 0.7 | 0.22 | 408.6 | 23 |
| Ti _{1x} Sc _x N | 0.5 | 472.2 | 110 | 170.4 | 230.7 | 174.6 | 0.76 | 0.2 | 418.3 | 25.9 |
| | 0.625 | 460.6 | 104.3 | 172.5 | 223.1 | 174.7 | 0.78 | 0.19 | 415.7 | 27 |
| | 0.75 | 439.5 | 104.6 | 168.2 | 216.2 | 167.9 | 0.78 | 0.19 | 400.2 | 26 |
| | 0.875 | 419.3 | 103.8 | 168.8 | 209 | 164.3 | 0.79 | 0.19 | 390.6 | 25.9 |
| | 1 | 389.5 | 104.2 | 166.8 | 199.3 | 156.7 | 0.79 | 0.19 | 372.5 | 25.1 |
| | 0 | 563.2 | 113.1 | 158.6 | 263.1 | 182.5 | 0.69 | 0.22 | 444.7 | 24.2 |
| | 0.125 | 477.2 | 124.6 | 142.5 | 242.1 | 155.2 | 0.64 | 0.24 | 383.5 | 19.7 |
| $Ti_{1-x}Y_xN$ | 0.25 | 433.4 | 103 | 133.7 | 213.1 | 145.5 | 0.68 | 0.22 | 355.6 | 20.3 |
| | 0.375 | 295.7 | 107.7 | 121.6 | 170.3 | 109.7 | 0.64 | 0.23 | 270.9 | 15.5 |
| | 0.5 | 272.5 | 77 | 121.4 | 142.2 | 111.3 | 0.78 | 0.19 | 264.8 | 19.6 |
| | 0.625 | 278.5 | 79.3 | 123.7 | 145.7 | 113.4 | 0.78 | 0.19 | 270.2 | 19.7 |
| | 0.75 | 293.5 | 83.1 | 126 | 153.2 | 117.2 | 0.77 | 0.2 | 280.2 | 19.8 |
| | 0.875 | 279.7 | 75.8 | 117.9 | 143.8 | 111.2 | 0.77 | 0.19 | 265.3 | 19.3 |
| | 1 | 318.5 | 76.8 | 122.6 | 157.4 | 121.9 | 0.77 | 0.19 | 290.7 | 20.6 |



Fig. 11. Projected density of states (PDOS) for the random solid solution $Ti_{0.375}Sc_{0.625}N$, which has the highest hardness. Red solid and green long-dashed lines represent the metallic t2g an eg states respectively while blue shortdashed lines indicate nitrogen p states. The Fermi energy is set to 0 eV.

binary ceramic systems, $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Y_xN$ ($0 \le x \le 1$) using first principles methods based on DFT, CE, and MC simulations. Owing to the similarity in the size, ionic radius, and electronegativity of Ti and Sc, a strong exothermic mixing is predicted in Ti_{1-x}Sc_xN, allowing the formation of four thermodynamically stable intermetallic phases: TiScN₂, TiSc₈N₉, TiSc₉N₁₀, and Ti₃Sc₂N₅. These novel compounds, for which stability is characterized in the phase diagram, are predicted to crystallize in layered rocksalt-type structures to minimize strain energy. Of these phases, Ti₃Sc₂N₅ uniquely maintains stability throughout a wide range of concentrations (0 to 50% Sc) and temperatures (0 to 500 K). In contrast to $Ti_{1-x}Sc_xN$, the system of $Ti_{1-x}Y_xN$ is found to exhibit strong endothermic mixing due to the large lattice mismatch between Ti and Y. Hence, solubility is achieved only at very low or high Y concentrations. Despite the insolubility at intermediate concentrations, Y atoms may be implemented at grain boundaries to improve oxidation resistance.

We have characterized the mechanical properties of $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Y_xN$, with the end members exhibiting Vickers hardness values of 23.4, 25.1, and 20.6 GPa respectively. The predicted intermetallics of the $Ti_{1-x}Sc_xN$ system are shown to display increased hardness with respect to the end members TiN and ScN. Of these compounds, $Ti_3Sc_2N_5$

achieves the highest hardness of 27.3 GPa. To compare these findings with the properties of the respective cation-disordered alloys occurring at high temperatures, we have studied the SQS's of $Ti_{1-x}Sc_xN$ and $Ti_{1-x}Y_xN$. The latter exhibits weakened mechanical properties due to significant volumetric expansion and decreased electron localization. In contrast, the former shows enhanced hardness, being directly related to an increase in C_{44} , at intermediate concentrations. A maximum hardness of about 27.0 GPa is achieved at a VEC of 8.4, which is in agreement with previous findings in related systems [7]. However, a slight decrease in hardness with respect to the ordered phases is observed due to structural distortions.

Lastly, to provide clear explanation of the trends in mechanical properties, we have studied the underlying electronic structure of Ti₁. _xSc_xN and Ti_{1-x}Y_xN using PDOS and COHP curves. Each system is characterized by strong hybridization of bonding character occurring at low energies, being related to σ -overlap of $d e_{\sigma}$ and 2p orbitals, and at higher energies some degree of (nearly) nonbonding $d t_{2g}$ states, for which occupation may be tuned by changes in VEC. The e_g states contribute to high hardness due to their shear-resistant nature within the rocksalt structure, whereas t_{2g} states cause decreased hardness as they favor shearing owing to increased overlap with equivalent orbitals of the 2nd-nearest neighbors through metal-metal bonding. Hence, we find that hardness is maximized at intermediate Sc concentrations, corresponding to VEC ranging from 8.4-8.6, due to enhanced d-p hybridization and minimized t_{2g} occupation, shown by the PDOS and COHP curves of $Ti_3Sc_2N_5$ and $Ti_{0.375}Sc_{0.625}N.$ In the case of $Ti_{1\mbox{-}x}Y_xN,$ maximum hardness may not be achieved, as structural distortions and volumetric expansion dominate over electronic effects.

We conclude that the high hardness and robust thermal stability of the Ti_{1-x}Sc_xN alloys make them promising candidates for improved hard coating applications. Moving forward, we suggest experimental synthesis by cathodic arc deposition or through reactive magnetron sputter deposition as previously demonstrated [107,108]. In addition to the direct practical applications of this work, the methodology developed here could be applied to discover next-generation structural and functional alloys, with mechanical properties finely tuned through controlled electron valency, using a purely materials-by-design approach derived from first-principles.

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